### P-Channel 20-V (D-S) MOSFET

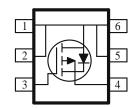
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)}m(OHM)$	$\mathbf{I}_{\mathbf{D}}(\mathbf{A})$		
	65 @ V <sub>CS</sub> =-4.5V	-4.5		
-20	$100 @ V_{CS} = -2.5V$	-4.2		
	150 @ V <sub>CS</sub> =-1.8V	-3.1		

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- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			-20	V		
Gate-Source Voltage		$V_{GS}$	±12	V		
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	] ] T_	-4.5			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	-3.6	A		
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	±20			
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	-1.7	A		
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$	D <sub>n</sub>	2.0	W		
Power Dissipation	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ТЪ	1.3			
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
M . I	4 . 5	р	62.5	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	$t \le 5 \text{ sec}$	$ m R_{?JA}$		°C/W		

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#### Notes

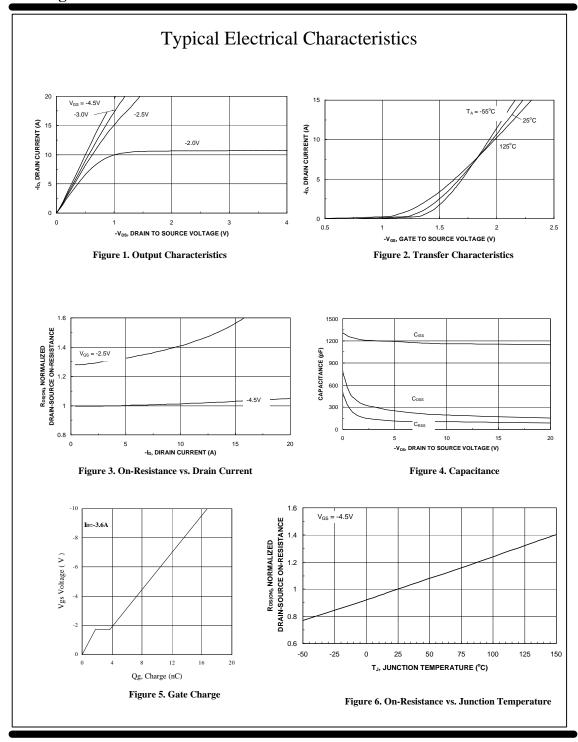
- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter		Test Conditions	Limits			TT .*4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-0.7				
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \ V, \ V_{GS} = \pm 12 \ V$			±100	nA	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uА	
	*DSS	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-5	uzs	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = -4.5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-15			A	
		$V_{GS} = -4.5 \text{ V}, I_{D} = -4.5 \text{A}$			65		
Drain-Source On-Resistance <sup>A</sup>	$r_{\mathrm{DS(on)}}$	$V_{GS} = -2.5 \text{ V}, I_D = -3.8 \text{ A}$			100	mOHM	
		$V_{GS} = -1.8 \text{ V}, I_D = -3.1 \text{ A}$			150		
Forward Tranconductance <sup>A</sup>	$g_{\mathrm{fs}}$	$V_{DS} = -10 \text{ V}, I_{D} = -4.5 \text{ A}$		11		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{\mathrm{g}}$	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		8.0			
Gate-Source Charge	$Q_{gs}$	$I_{DS} = -4.5 \text{ A}$		1.8		nC	
Gate-Drain Charge	$Q_{\mathrm{gd}}$	I <sub>D</sub> = -4.5 A		1.9			
Turn-On Delay Time	$t_{d(on)}$			22			
Rise Time	$t_{\rm r}$	$V_{DD} = -10 \text{ V}, R_L = 6 \text{ O}, ID = -1 \text{ A},$		35		nS	
Turn-Off Delay Time	$t_{d(off)}$	VGEN = -4.5 V		45		1113	
Fall-Time	$t_{ m f}$			25			

#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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## Typical Electrical Characteristics

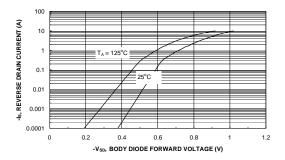
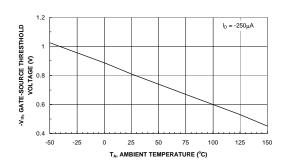


Figure 7. Source-Drain Diode Forward Voltage

Figure 8. On-Resistance with Gate to Source Voltage



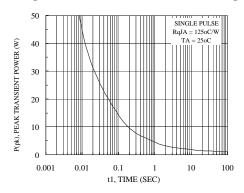


Figure 9. Vth Gate to Source Voltage Vs Temperature

Figure 10. Single Pulse Maximum Power Dissipation

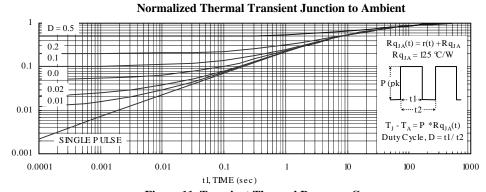
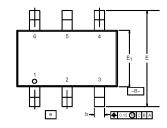
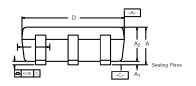


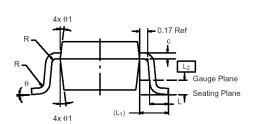
Figure 11. Transient Thermal Response Curve

# Package Information

TSOP-6: 6LEAD







	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	-	0.043
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004
A <sub>2</sub>	0.84	-	1.00	0.033	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
Е	2.70	2.85	2.98	0.106	0.112	0.117
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067
е	1.00 BSC			0.0394 BSC		
L	0.35	-	0.50	0.014	-	0.020
L <sub>1</sub>	0.60 Ref			0.024 Ref		
$L_2$		0.25 BSC 0.010 BSC				
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
$\theta_1$	7° Nom 7° Nom					